Roll No. Total Pages: 03 43140 BT-3/D-22 COMPUTER SCIENCE AND ENGINEERING Digital Electronics ES-207-A [Maximum Marks: 75 Time: Three Hours Note: Attempt Five questions in all, selecting at least one question from each Unit. All questions carry equal marks. Convert the following decimal numbers in binary: 2 1. (a) 28.6 (i) 31.567. (ii) Perform the following operations using (b) 2's complement: 5 (i) 48 - 23(ii) 23 - (-67). Explain the conversion of AND operation into OR (c) operation with the help of De-Morgan theorem. 5 Simplify (A + B)(A' + C) to minimum number of (d) literals. 3

Explain the different properties of logic families.

P.T.O.

Explain the working of TTL NAND gate.

2.

(a)

(3-34/5) I-43140

(b)	Minimize the expression using K-Map
	$F = \Pi M(1, 2, 5, 6, 8, 9, 10) . d(3, 7, 15).$
	Also realize the obtained expression using AOI
	logic.
Unit II	
(a)	State and explain the working of BCD adder with
	its logic diagram.
(b)	Design a 3-to-8 decoder. 5
(a)	Design a 3 bit odd parity generator. 5
(b)	What do you mean by multiplexer? Explain the
	working of $n:1$ mux. Design a multiplexer tree for
	32 1 mux using 8 : 1 and 2 : 1 mux. 10
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Unit III

- 5. (a) Explain the working of J-K flip-flop. What is race around condition in J-K flip-flop? How can it be solved by master slave flip-flop?

 8
 - (b) Convert S-R flip-flop in D flip-flop. 7
- 6. (a) Design a synchronous mod-6 counter. Use J-K flipflop for designing the counter.
 - (b) What do you mean by register? Draw and explain the logic diagram of serial in serial out shift right register.

L-43140

3.

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Unit IV

- 7. (a) Explain the working of R-2R ladder Digital toAnalog Converter.8
 - (b) Describe the working of successive approximation type ADC.
- 8. (a) Draw the diagram of basic RAM cell. Explain SRAM and DRAM memories. Also describe, how read and write operations occur in RAM.
 - (b) Draw the block diagram of memory device. Mention the working of ROM. Also draw diagram showing ROM array.